

# DATA SHEET



## **BAS32L** High-speed diode

Product specification  
Supersedes data of April 1996

1996 Sep 10

# High-speed diode

# BAS32L

## FEATURES

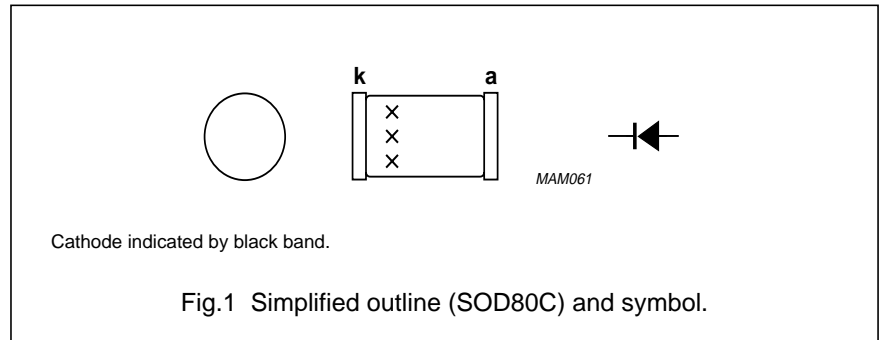
- Small hermetically sealed glass SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 75 V
- Repetitive peak forward current: max. 450 mA.

## APPLICATIONS

- High-speed switching
- Fast logic applications.

## DESCRIPTION

The BAS32L is a high-speed switching diode fabricated in planar technology, and encapsulated in the small hermetically sealed glass SOD80C SMD package.



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage		–	75	V
$V_R$	continuous reverse voltage		–	75	V
$I_F$	continuous forward current	see Fig.2; note 1	–	200	mA
$I_{FRM}$	repetitive peak forward current		–	450	mA
$I_{FSM}$	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\ \mu\text{s}$ $t = 1\ \text{ms}$ $t = 1\ \text{s}$	–	4 1 0.5	A A A
$P_{tot}$	total power dissipation	$T_{amb} = 25\text{ °C}$ ; note 1	–	500	mW
$T_{stg}$	storage temperature		–65	+200	°C
$T_j$	junction temperature		–	200	°C

## Note

1. Device mounted on an FR4 printed-circuit board.

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**ELECTRICAL CHARACTERISTICS**

$T_j = 25\text{ }^\circ\text{C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage	see Fig.3			
		$I_F = 5\text{ mA}$	620	750	mV
		$I_F = 100\text{ mA}$	–	1000	mV
		$I_F = 100\text{ mA}; T_j = 100\text{ }^\circ\text{C}$	–	930	mV
$I_R$	reverse current	see Fig.5			
		$V_R = 20\text{ V}$	–	25	nA
		$V_R = 75\text{ V}$	–	5	$\mu\text{A}$
		$V_R = 20\text{ V}; T_j = 150\text{ }^\circ\text{C}$	–	50	$\mu\text{A}$
		$V_R = 75\text{ V}; T_j = 150\text{ }^\circ\text{C}$	–	100	$\mu\text{A}$
$V_{(BR)R}$	reverse breakdown voltage	$I_R = 100\text{ }\mu\text{A}$	100	–	V
$C_d$	diode capacitance	$f = 1\text{ MHz}; V_R = 0$ ; see Fig.6		2	pF
$t_{rr}$	reverse recovery time	when switched from $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}; R_L = 100\text{ }\Omega$ ; measured at $I_R = 1\text{ mA}$ ; see Fig.7		4	ns
$V_{fr}$	forward recovery voltage	when switched from $I_F = 50\text{ mA}$ ; $t_r = 20\text{ ns}$ ; see Fig.8	–	2.5	V

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point		300	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	350	K/W

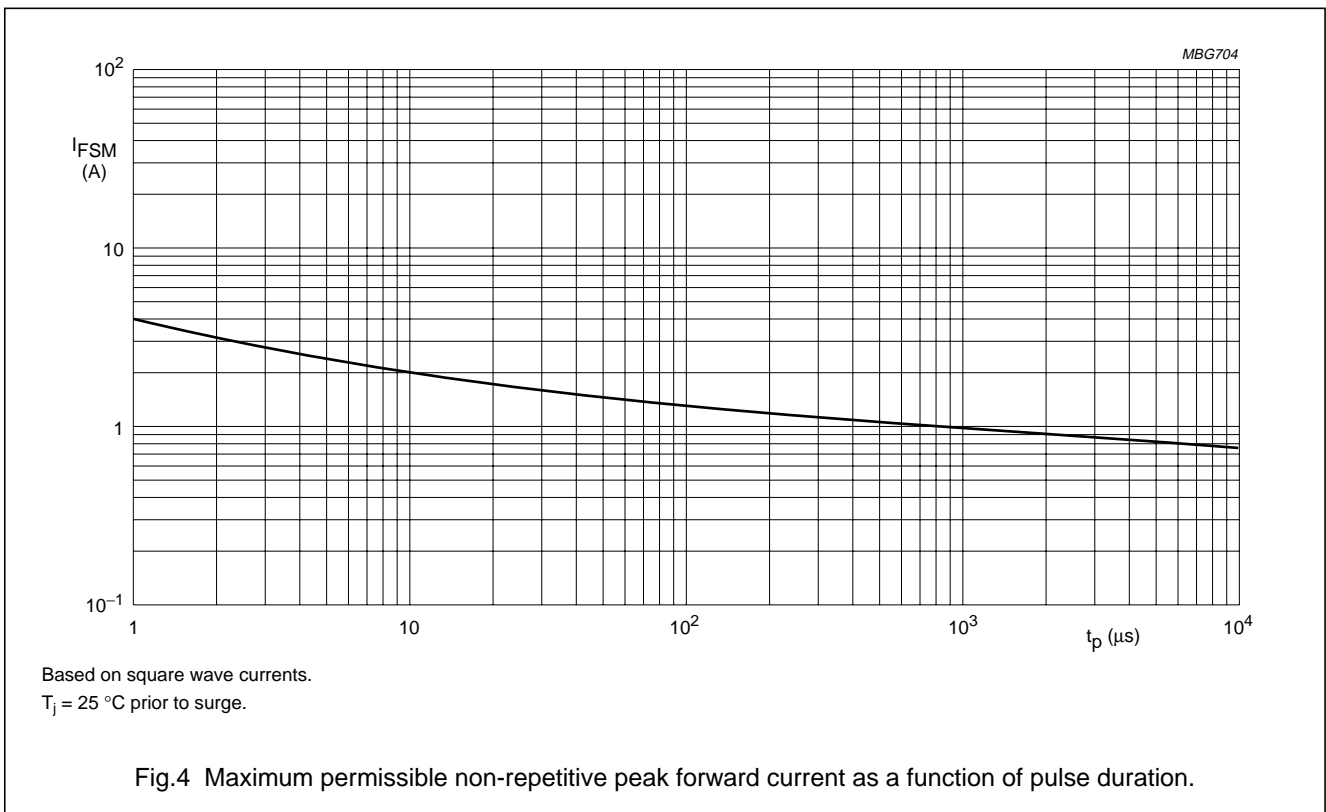
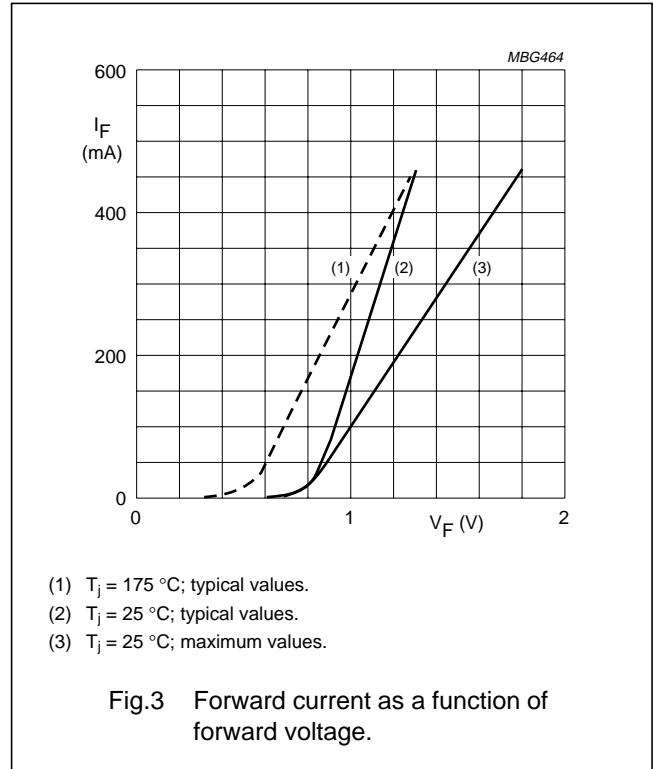
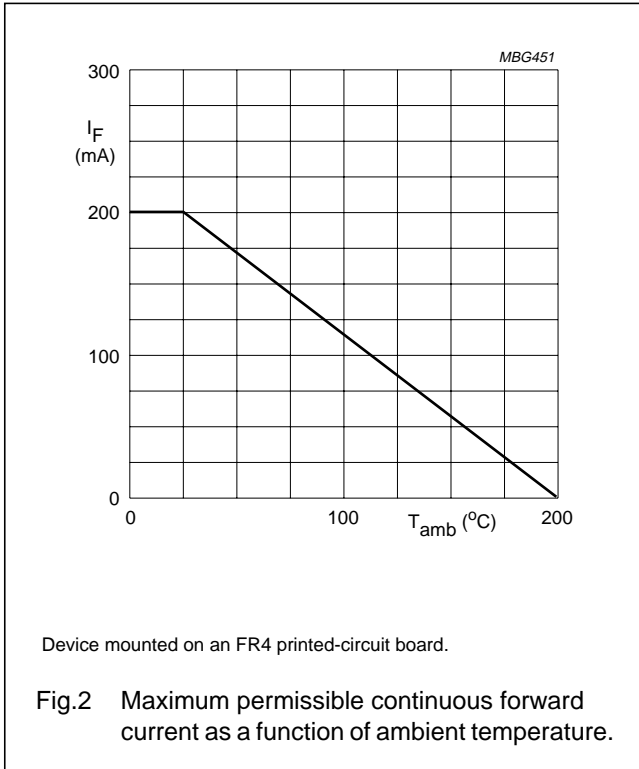
**Note**

1. Device mounted on an FR4 printed-circuit board.

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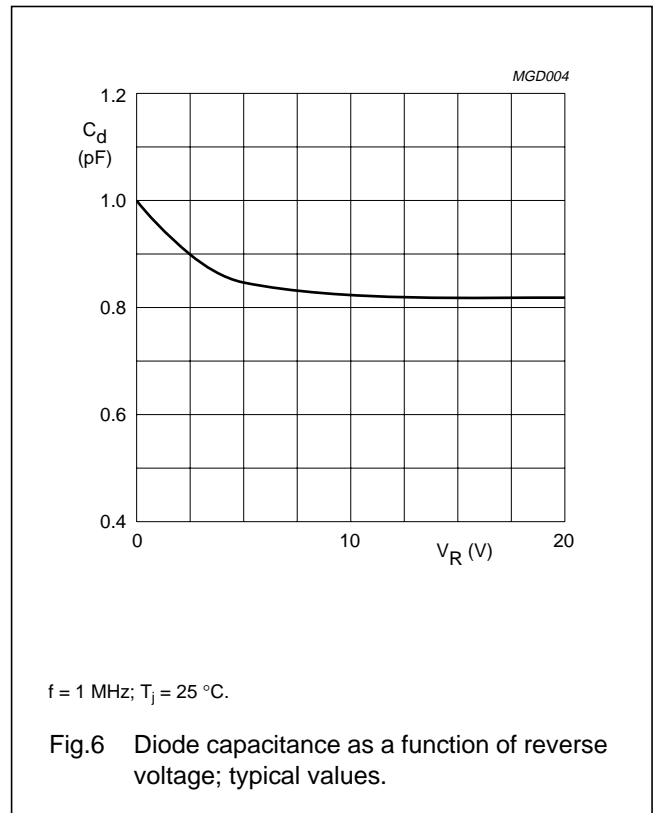
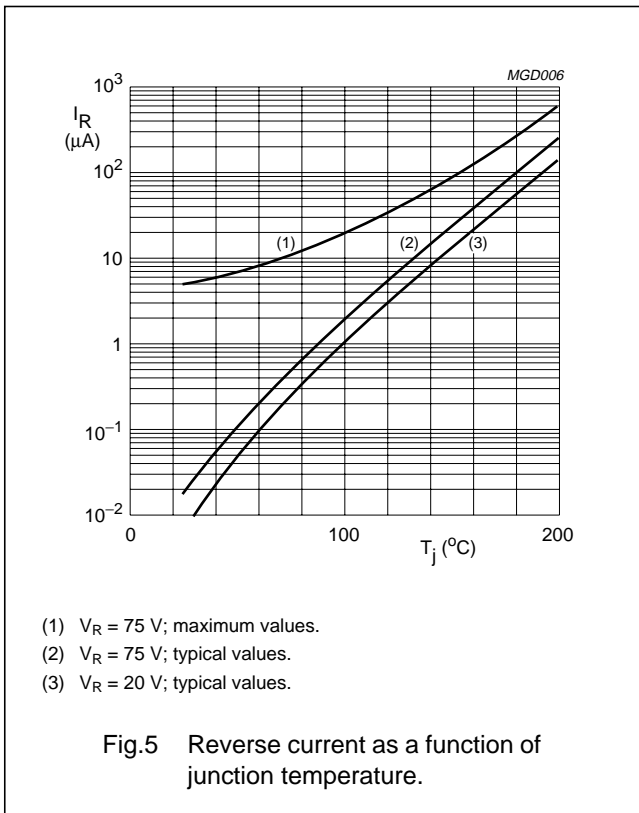
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GRAPHICAL DATA



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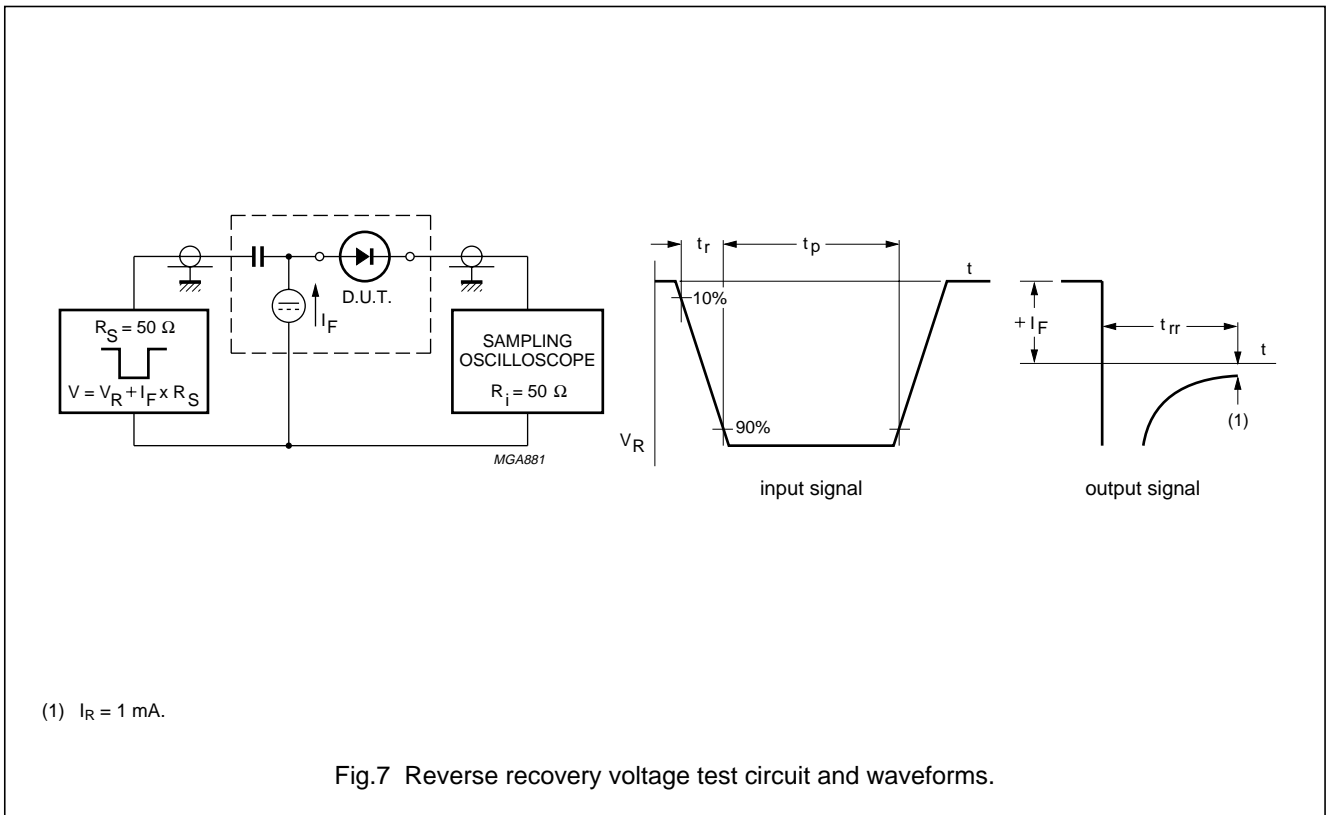


Fig.7 Reverse recovery voltage test circuit and waveforms.

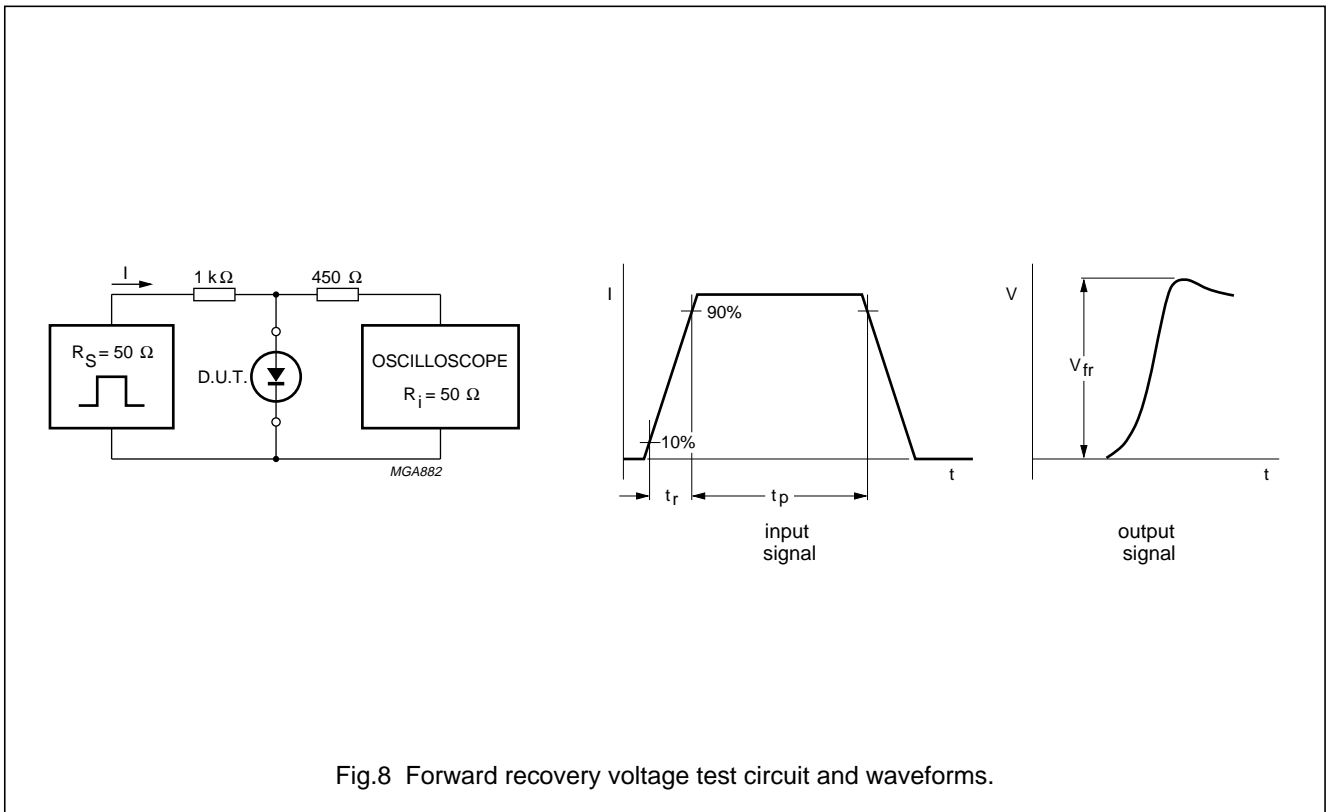
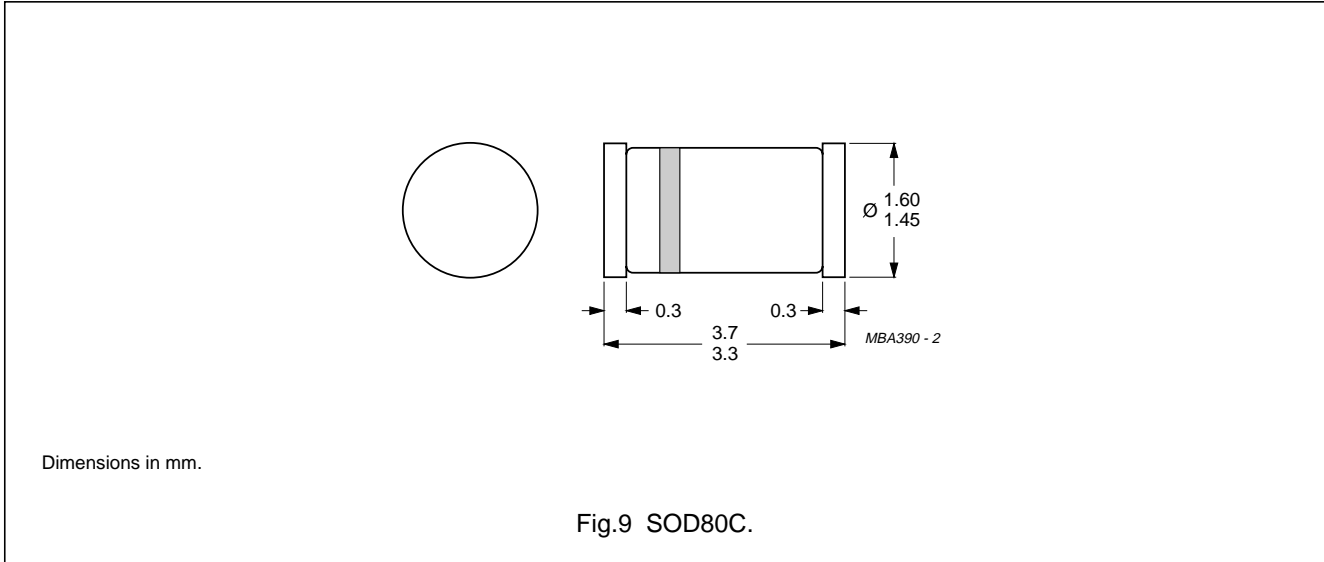


Fig.8 Forward recovery voltage test circuit and waveforms.

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PACKAGE OUTLINE



DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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